

S32 2	138	264/405.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S32 3	280	264/430.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S32 4	235	264/434.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S32 5	1326	264/332.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S32 6	129	264/682.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S32 7	103	264/683.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S32 8	254	501/91.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S32 9	681	501/92.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S33 0	288	501/93.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S33 1	482	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28

S33 2	0	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and sintering and EFAS	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S33 3	0	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and EFAS	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S33 4	169	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and electric adj field	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S33 5	169	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and (electric adj field)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S33 6	60	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S33 7	138	264/405.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S33 8	280	264/430.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S33 9	235	264/434.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S34 0	1326	264/332.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S34 1	129	264/682.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28

S34 2	103	264/683.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S34 3	254	501/91.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S34 4	681	501/92.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S34 5	288	501/93.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S34 6	490	(S337 or S338 or S339 or S340 or S341 or S342 or S343 or S344 or S345) and (silicon adj nitride) and (silicon adj carbide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S34 7	341	(S337 or S338 or S339 or S340 or S341 or S342 or S343 or S344 or S345) and (silicon adj nitride) and (silicon adj carbide) and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S34 8	0	(S337 or S338 or S339 or S340 or S341 or S342 or S343 or S344 or S345) and (silicon adj nitride) and (silicon adj carbide) and sintering and electric	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S34 9	97	(S337 or S338 or S339 or S340 or S341 or S342 or S343 or S344 or S345) and (silicon adj nitride) and (silicon adj carbide) and sintering and electric	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S35 0	84	(S337 or S338 or S339 or S340 or S341 or S342 or S343 or S344 or S345) and ((silicon adj nitride) same (silicon adj carbide)) and sintering and electric	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S35 1	0	(S337 or S338 or S339 or S340 or S341 or S342 or S343 or S344 or S345) and ((silicon adj nitride) same (silicon adj carbide)) and (electric same field same assisted same sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28

S35 2	8	(S337 or S338 or S339 or S340 or S341 or S342 or S343 or S344 or S345) and ((silicon adj nitride) same (silicon adj carbide)) and (electric same field) and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S35 3	138	264/405.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S35 4	280	264/430.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S35 5	235	264/434.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S35 6	1326	264/332.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S35 7	129	264/682.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S35 8	103	264/683.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S35 9	254	501/91.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S36 0	681	501/92.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S36 1	288	501/93.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28

S36 2	490	(S353 or S354 or S355 or S356 or S357 or S358 or S359 or S360 or S361) and (silicon adj nitride) and (silicon adj carbide) and wan.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S36 3	1	(S353 or S354 or S355 or S356 or S357 or S358 or S359 or S360 or S361) and (silicon adj nitride) and (silicon adj carbide) and wan.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S36 4	1	(S353 or S354 or S355 or S356 or S357 or S358 or S359 or S360 or S361) and (silicon adj nitride) and (silicon adj carbide) and gasch.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S36 5	1	(S353 or S354 or S355 or S356 or S357 or S358 or S359 or S360 or S361) and (silicon adj nitride) and (silicon adj carbide) and mukherjee.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S36 6	13	(silicon adj nitride) and (silicon adj carbide) and mukherjee.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S36 7	20	(silicon adj nitride) and (silicon adj carbide) and wan.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S36 8	5	(silicon adj nitride) and (silicon adj carbide) and gasch.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S36 9	138	264/405.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S37 0	280	264/430.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S37 1	235	264/434.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28

S37 2	1326	264/332.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR .	OFF	2005/11/19 14:28
S37 3	129	264/682.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S37 4	103	264/683.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S37 5	254	501/91.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S37 6	681	501/92.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S37 7	288	501/93.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S37 8	1	(S369 or S370 or S371 or S372 or S373 or S374 or S375 or S376 or S377) and (silicon adj nitride) and (silicon adj carbide) and (electric adj field adj assisted adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S37 9	1	(S369 or S370 or S371 or S372 or S373 or S374 or S375 or S376 or S377) and (silicon adj nitride) and (silicon adj carbide) and (electric adj field adj assisted adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S38 0	6	(S369 or S370 or S371 or S372 or S373 or S374 or S375 or S376 or S377) and (electric adj field adj assisted adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR .	OFF	2005/11/19 14:28
S38 1	1338	(S369 or S370 or S371 or S372 or S373 or S374 or S375 or S376 or S377) and (spark plasma sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28

S38 2	4	(S369 or S370 or S371 or S372 or S373 or S374 or S375 or S376 or S377) and (silicon adj nitride) and (silicon adj carbide) and (spark adj plasma adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S38 3	0	(S369 or S370 or S371 or S372 or S373 or S374 or S375 or S376 or S377) and (silicon adj nitride) and (silicon adj carbide) and (plasma adj activated adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S38 4	1	(S369 or S370 or S371 or S372 or S373 or S374 or S375 or S376 or S377) and (silicon adj nitride) and (silicon adj carbide) and (field adj assisted adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S38 5	341	(S369 or S370 or S371 or S372 or S373 or S374 or S375 or S376 or S377) and (silicon adj nitride) and (silicon adj carbide) and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S38 6	150	(S369 or S370 or S371 or S372 or S373 or S374 or S375 or S376 or S377) and (silicon adj nitride).clm. and (silicon adj carbide).clm. and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S38 7	9	("5352641" "5468697" "5525556" "5616527" "5643843" "5648028" "5767025" "5902761" "5912200").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/11/19 14:28
S38 8	126	(S369 or S370 or S371 or S372 or S373 or S374 or S375 or S376 or S377) and (silicon adj nitride) and (silicon adj carbide) and sintering and ((sintering adj aid) or (densification adj aid))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S38 9	63	(S369 or S370 or S371 or S372 or S373 or S374 or S375 or S376 or S377) and (silicon adj nitride).clm. and (silicon adj carbide).clm. and sintering and ((sintering adj aid) or (densification adj aid))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S39 0	15	("4187116").URPN.	USPAT	OR	OFF	2005/11/19 14:28
S39 1	7	"02160669"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28

S39 2	11	"6254940"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S39 3	16	"6420293"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S39 4	138	264/405.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S39 5	280	264/430.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S39 6	235	264/434.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S39 7	1326	264/332.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S39 8	129	264/682.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S39 9	103	264/683.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S40 0	254	501/91.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S40 1	681	501/92.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28

S40 2	288	501/93.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S40 3	482	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S40 4	0	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and sintering and EFAS	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S40 5	0	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and EFAS	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S40 6	169	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and electric adj field	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S40 7	169	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and (electric adj field)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S40 8	138	264/405.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S40 9	280	264/430.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S41 0	235	264/434.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S41 1	1326	264/332.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28

S41 2	129	264/682.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S41 3	103	264/683.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S41 4	254	501/91.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S41 5	681	501/92.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S41 6	288	501/93.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S41 7	490	(S408 or S409 or S410 or S411 or S412 or S413 or S414 or S415 or S416) and (silicon adj nitride) and (silicon adj carbide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S41 8	341	(S408 or S409 or S410 or S411 or S412 or S413 or S414 or S415 or S416) and (silicon adj nitride) and (silicon adj carbide) and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S41 9	0	(S408 or S409 or S410 or S411 or S412 or S413 or S414 or S415 or S416) and (silicon adj nitride) and (silicon adj carbide) and sintering and electric	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S42 0	84	(S408 or S409 or S410 or S411 or S412 or S413 or S414 or S415 or S416) and ((silicon adj nitride) same (silicon adj carbide)) and sintering and electric	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S42 1	0	(S408 or S409 or S410 or S411 or S412 or S413 or S414 or S415 or S416) and ((silicon adj nitride) same (silicon adj carbide)) and (electric same field same assisted same sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28

S42 2	138	264/405.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S42 3	280	264/430.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S42 4	235	264/434.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S42 5	1326	264/332.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S42 6	129	264/682.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S42 7	103	264/683.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S42 8	254	501/91.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S42 9	681	501/92.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S43 0	288	501/93.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S43 1	490	(S422 or S423 or S424 or S425 or S426 or S427 or S428 or S429 or S430) and (silicon adj nitride) and (silicon adj carbide) andwan.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28

S43 2	1	(S422 or S423 or S424 or S425 or S426 or S427 or S428 or S429 or S430) and (silicon adj nitride) and (silicon adj carbide) and wan.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR .	OFF	2005/11/19 14:28
S43 3	1	(S422 or S423 or S424 or S425 or S426 or S427 or S428 or S429 or S430) and (silicon adj nitride) and (silicon adj carbide) and gasch.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S43 4	1	(S422 or S423 or S424 or S425 or S426 or S427 or S428 or S429 or S430) and (silicon adj nitride) and (silicon adj carbide) and mukherjee.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S43 5	138	264/405.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S43 6	280	264/430.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S43 7	235	264/434.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S43 8	1326	264/332.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S43 9	129	264/682.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S44 0	103	264/683.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR .	OFF	2005/11/19 14:28
S44 1	254	501/91.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28

S44 2	681	501/92.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S44 3	288	501/93.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S44 4	1	(S435 or S436 or S437 or S438 or S439 or S440 or S441 or S442 or S443) and (silicon adj nitride) and (silicon adj carbide) and (electric adj field adj assisted adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S44 5	1	(S435 or S436 or S437 or S438 or S439 or S440 or S441 or S442 or S443) and (silicon adj nitride) and (silicon adj carbide) and (electric adj field adj assisted adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S44 6	1338	(S435 or S436 or S437 or S438 or S439 or S440 or S441 or S442 or S443) and (spark plasma sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S44 7	0	(S435 or S436 or S437 or S438 or S439 or S440 or S441 or S442 or S443) and (silicon adj nitride) and (silicon adj carbide) and (plasma adj activated adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S44 8	1	(S435 or S436 or S437 or S438 or S439 or S440 or S441 or S442 or S443) and (silicon adj nitride) and (silicon adj carbide) and (field adj assisted adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S44 9	126	(S435 or S436 or S437 or S438 or S439 or S440 or S441 or S442 or S443) and (silicon adj nitride) and (silicon adj carbide) and sintering and ((sintering adj aid) or (densification adj aid))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S45 0	60	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S45 1	97	(S408 or S409 or S410 or S411 or S412 or S413 or S414 or S415 or S416) and (silicon adj nitride) and (silicon adj carbide) and sintering and electric	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28

S45 2	8	(S408 or S409 or S410 or S411 or S412 or S413 or S414 or S415 or S416) and ((silicon adj nitride) same (silicon adj carbide)) and (electric same field) and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S45 3	13	(silicon adj nitride) and (silicon adj carbide) and mukherjee.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S45 4	20	(silicon adj nitride) and (silicon adj carbide) and wan.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S45 5	5	(silicon adj nitride) and (silicon adj carbide) and gasch.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S45 6	6	(S435 or S436 or S437 or S438 or S439 or S440 or S441 or S442 or S443) and (electric adj field adj assisted adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S45 7	4	(S435 or S436 or S437 or S438 or S439 or S440 or S441 or S442 or S443) and (silicon adj nitride) and (silicon adj carbide) and (spark adj plasma adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S45 8	9	("5352641" "5468697" "5525556" "5616527" "5643843" "5648028" "5767025" "5902761" "5912200").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/11/19 14:28
S45 9	63	(S435 or S436 or S437 or S438 or S439 or S440 or S441 or S442 or S443) and (silicon adj nitride).clm. and (silicon adj carbide).clm. and sintering and ((sintering adj aid) or (densification adj aid))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S46 0	15	("4187116").URPN.	USPAT	OR	OFF	2005/11/19 14:28
S46 1	7	"02160669"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28

S46 2	11	"6254940"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S46 3	16	"6420293"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S46 4	150	(S435 or S436 or S437 or S438 or S439 or S440 or S441 or S442 or S443) and (silicon adj nitride).clm. and (silicon adj carbide).clm. and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S46 5	341	(S435 or S436 or S437 or S438 or S439 or S440 or S441 or S442 or S443) and (silicon adj nitride) and (silicon adj carbide) and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S46 6	12	("5039632" "5386006" "5424126" "6025454" "6242626" "6478994")".PN"	USPAT	OR	OFF	2005/11/19 14:28
S46 7	7	"5884134"	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/11/19 14:28
S46 8	1	"58084134"	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/11/19 14:28
S46 9	3	"5684134"	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/11/19 14:28
S47 0	1	"56084134"	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/11/19 14:28
S47 1	1	"58084134"	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/11/19 14:28

S47 2	2	"58084184"	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/11/19 14:28
S47 3	1	"60145910"	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/11/19 14:28
S47 4	8	"6422041"	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/11/19 14:28
S47 5	138	264/405.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S47 6	280	264/430.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S47 7	235	264/434.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S47 8	1326	264/332.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S47 9	129	264/682.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S48 0	103	264/683.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S48 1	254	501/91.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28

S48 2	681	501/92.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S48 3	288	501/93.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S48 4	482	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S48 5	0	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and sintering and EFAS	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S48 6	0	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and EFAS	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S48 7	169	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and electric adj field	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S48 8	169	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and (electric adj field)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S48 9	138	264/405.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S49 0	280	264/430.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S49 1	235	264/434.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28

S49 2	1326	264/332.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S49 3	129	264/682.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S49 4	103	264/683.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S49 5	254	501/91.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S49 6	681	501/92.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S49 7	288	501/93.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S49 8	490	(S489 or S490 or S491 or S492 or S493 or S494 or S495 or S496 or S497) and (silicon adj nitride) and (silicon adj carbide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S49 9	341	(S489 or S490 or S491 or S492 or S493 or S494 or S495 or S496 or S497) and (silicon adj nitride) and (silicon adj carbide) and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S50 0	0	(S489 or S490 or S491 or S492 or S493 or S494 or S495 or S496 or S497) and (silicon adj nitride) and (silicon adj carbide) and sintering and electric	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S50 1	84	(S489 or S490 or S491 or S492 or S493 or S494 or S495 or S496 or S497) and ((silicon adj nitride) same (silicon adj carbide)) and sintering and electric	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28

S50 2	0	(S489 or S490 or S491 or S492 or S493 or S494 or S495 or S496 or S497) and ((silicon adj nitride) same (silicon adj carbide)) and (electric same field same assisted same sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S50 3	138	264/405.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S50 4	280	264/430.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S50 5	235	264/434.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S50 6	1326	264/332.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S50 7	129	264/682.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S50 8	103	264/683.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S50 9	254	501/91.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S51 0	681	501/92.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S51 1	288	501/93.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28

S51 2	490	(S503 or S504 or S505 or S506 or S507 or S508 or S509 or S510 or S511) and (silicon adj nitride) and (silicon adj carbide) and wan.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S51 3	1	(S503 or S504 or S505 or S506 or S507 or S508 or S509 or S510 or S511) and (silicon adj nitride) and (silicon adj carbide) and wan.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S51 4	1	(S503 or S504 or S505 or S506 or S507 or S508 or S509 or S510 or S511) and (silicon adj nitride) and (silicon adj carbide) and gasch.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S51 5	1	(S503 or S504 or S505 or S506 or S507 or S508 or S509 or S510 or S511) and (silicon adj nitride) and (silicon adj carbide) and mukherjee.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S51 6	138	264/405.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S51 7	280	264/430.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S51 8	235	264/434.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S51 9	1326	264/332.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S52 0	129	264/682.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S52 1	103	264/683.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28

S52 2	254	501/91.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S52 3	681	501/92.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S52 4	288	501/93.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S52 5	1	(S516 or S517 or S518 or S519 or S520 or S521 or S522 or S523 or S524) and (silicon adj nitride) and (silicon adj carbide) and (electric adj field adj assisted adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S52 6	1	(S516 or S517 or S518 or S519 or S520 or S521 or S522 or S523 or S524) and (silicon adj nitride) and (silicon adj carbide) and (electric adj field adj assisted adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S52 7	1338	(S516 or S517 or S518 or S519 or S520 or S521 or S522 or S523 or S524) and (spark plasma sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S52 8	0	(S516 or S517 or S518 or S519 or S520 or S521 or S522 or S523 or S524) and (silicon adj nitride) and (silicon adj carbide) and (plasma adj activated adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S52 9	1	(S516 or S517 or S518 or S519 or S520 or S521 or S522 or S523 or S524) and (silicon adj nitride) and (silicon adj carbide) and (field adj assisted adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S53 0	126	(S516 or S517 or S518 or S519 or S520 or S521 or S522 or S523 or S524) and (silicon adj nitride) and (silicon adj carbide) and sintering and ((sintering adj aid) or (densification adj aid))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S53 1	138	264/405.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28

S53 2	280	264/430.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S53 3	235	264/434.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S53 4	1326	264/332.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S53 5	129	264/682.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S53 6	103	264/683.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S53 7	254	501/91.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S53 8	681	501/92.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S53 9	288	501/93.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S54 0	482	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S54 1	0	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and sintering and EFAS	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28

S54 2	0	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and EFAS	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S54 3	169	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and electric adj field	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S54 4	169	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and (electric adj field)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S54 5	138	264/405.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S54 6	280	264/430.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S54 7	235	264/434.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S54 8	1326	264/332.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S54 9	129	264/682.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S55 0	103	264/683.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S55 1	254	501/91.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28

S55 2	681	501/92.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S55 3	288	501/93.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S55 4	490	(S545 or S546 or S547 or S548 or S549 or S550 or S551 or S552 or S553) and (silicon adj nitride) and (silicon adj carbide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S55 5	341	(S545 or S546 or S547 or S548 or S549 or S550 or S551 or S552 or S553) and (silicon adj nitride) and (silicon adj carbide) and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S55 6	0	(S545 or S546 or S547 or S548 or S549 or S550 or S551 or S552 or S553) and (silicon adj nitride) and (silicon adj carbide) and sintering and electric	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S55 7	84	(S545 or S546 or S547 or S548 or S549 or S550 or S551 or S552 or S553) and ((silicon adj nitride) same (silicon adj carbide)) and sintering and electric	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S55 8	0	(S545 or S546 or S547 or S548 or S549 or S550 or S551 or S552 or S553) and ((silicon adj nitride) same (silicon adj carbide)) and (electric same field same assisted same sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S55 9	138	264/405.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S56 0	280	264/430.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S56 1	235	264/434.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28

S56 2	1326	264/332.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S56 3	129	264/682.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S56 4	103	264/683.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S56 5	254	501/91.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S56 6	681	501/92.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S56 7	288	501/93.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S56 8	490	(S559 or S560 or S561 or S562 or S563 or S564 or S565 or S566 or S567) and (silicon adj nitride) and (silicon adj carbide) and wan.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S56 9	1	(S559 or S560 or S561 or S562 or S563 or S564 or S565 or S566 or S567) and (silicon adj nitride) and (silicon adj carbide) and wan.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S57 0	1	(S559 or S560 or S561 or S562 or S563 or S564 or S565 or S566 or S567) and (silicon adj nitride) and (silicon adj carbide) and gasch.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S57 1	1	(S559 or S560 or S561 or S562 or S563 or S564 or S565 or S566 or S567) and (silicon adj nitride) and (silicon adj carbide) and mukherjee.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28

S57 2	138	264/405.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S57 3	280	264/430.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S57 4	235	264/434.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S57 5	1326	264/332.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S57 6	129	264/682.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S57 7	103	264/683.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S57 8	254	501/91.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S57 9	681	501/92.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S58 0	288	501/93.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S58 1	1	(S572 or S573 or S574 or S575 or S576 or S577 or S578 or S579 or S580) and (silicon adj nitride) and (silicon adj carbide) and(electric adj field adj assisted adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28

S58 2	1	(S572 or S573 or S574 or S575 or S576 or S577 or S578 or S579 or S580) and (silicon adj nitride) and (silicon adj carbide) and (electric adj field adj assisted adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S58 3	1338	(S572 or S573 or S574 or S575 or S576 or S577 or S578 or S579 or S580) and (spark plasma sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S58 4	0	(S572 or S573 or S574 or S575 or S576 or S577 or S578 or S579 or S580) and (silicon adj nitride) and (silicon adj carbide) and (plasma adj activated adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S58 5	1	(S572 or S573 or S574 or S575 or S576 or S577 or S578 or S579 or S580) and (silicon adj nitride) and (silicon adj carbide) and (field adj assisted adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S58 6	126	(S572 or S573 or S574 or S575 or S576 or S577 or S578 or S579 or S580) and (silicon adj nitride) and (silicon adj carbide) and sintering and ((sintering adj aid) or (densification adj aid))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S58 7	1	"58084134"	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/11/19 14:28
S58 8	1	"56084134"	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/11/19 14:28
S58 9	1	"58084134"	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/11/19 14:28
S59 0	1	"60145910"	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/11/19 14:28
S59 1	60	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28

S59 2	97	(S489 or S490 or S491 or S492 or S493 or S494 or S495 or S496 or S497) and (silicon adj nitride) and (silicon adj carbide) and sintering and electric	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S59 3	8	(S489 or S490 or S491 or S492 or S493 or S494 or S495 or S496 or S497) and ((silicon adj nitride) same (silicon adj carbide)) and (electric same field) and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S59 4	13	(silicon adj nitride) and (silicon adj carbide) and mukherjee.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S59 5	20	(silicon adj nitride) and (silicon adj carbide) and wan.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S59 6	5	(silicon adj nitride) and (silicon adj carbide) and gasch.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S59 7	6	(S516 or S517 or S518 or S519 or S520 or S521 or S522 or S523 or S524) and (electric adj field adj assisted adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S59 8	4	(S516 or S517 or S518 or S519 or S520 or S521 or S522 or S523 or S524) and (silicon adj nitride) and (silicon adj carbide) and (spark adj plasma adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S59 9	9	("5352641" "5468697" "5525556" "5616527" "5643843" "5648028" "5767025" "5902761" "5912200").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/11/19 14:28
S60 0	63	(S516 or S517 or S518 or S519 or S520 or S521 or S522 or S523 or S524) and (silicon adj nitride).clm. and (silicon adj carbide).clm. and sintering and ((sintering adj aid) or (densification adj aid))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S60 1	15	("4187116").URPN.	USPAT	OR	OFF	2005/11/19 14:28

S60 2	7	"02160669"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S60 3	11	"6254940"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S60 4	16	"6420293"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S60 5	60	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S60 6	97	(S545 or S546 or S547 or S548 or S549 or S550 or S551 or S552 or S553) and (silicon adj nitride) and (silicon adj carbide) and sintering and electric	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S60 7	8	(S545 or S546 or S547 or S548 or S549 or S550 or S551 or S552 or S553) and ((silicon adj nitride) same (silicon adj carbide)) and (electric same field) and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S60 8	13	(silicon adj nitride) and (silicon adj carbide) and mukherjee.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S60 9	20	(silicon adj nitride) and (silicon adj carbide) and wan.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S61 0	5	(silicon adj nitride) and (silicon adj carbide) and gasch.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S61 1	6	(S572 or S573 or S574 or S575 or S576 or S577 or S578 or S579 or S580) and (electric adj field adj assisted adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28

S61 2	4	(S572 or S573 or S574 or S575 or S576 or S577 or S578 or S579 or S580) and (silicon adj nitride) and (silicon adj carbide) and (spark adj plasma adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S61 3	9	("5352641" "5468697" "5525556" "5616527" "5643843" "5648028" "5767025" "5902761" "5912200").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/11/19 14:28
S61 4	63	(S572 or S573 or S574 or S575 or S576 or S577 or S578 or S579 or S580) and (silicon adj nitride).clm. and (silicon adj carbide).clm. and sintering and ((sintering adj aid) or (densification adj aid))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S61 5	15	("4187116").URPN.	USPAT	OR	OFF	2005/11/19 14:28
S61 6	7	"02160669"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S61 7	11	"6254940"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S61 8	16	"6420293"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S61 9	12	("5039632" "5386006" "5424126" "6025454" "6242626" "6478994").PN"	USPAT	OR	OFF	2005/11/19 14:28
S62 0	7	"5884134"	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/11/19 14:28
S62 1	3	"5684134"	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/11/19 14:28
S62 2	2	"58084184"	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/11/19 14:28

S62 3	8	"6422041"	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/11/19 14:28
S62 4	150	(S516 or S517 or S518 or S519 or S520 or S521 or S522 or S523 or S524) and (silicon adj nitride).clm. and (silicon adj carbide).clm. and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S62 5	150	(S572 or S573 or S574 or S575 or S576 or S577 or S578 or S579 or S580) and (silicon adj nitride).clm. and (silicon adj carbide).clm. and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S62 6	341	(S516 or S517 or S518 or S519 or S520 or S521 or S522 or S523 or S524) and (silicon adj nitride) and (silicon adj carbide) and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S62 7	341	(S572 or S573 or S574 or S575 or S576 or S577 or S578 or S579 or S580) and (silicon adj nitride) and (silicon adj carbide) and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S62 8	22	("4097293" "4141740" "4146379" "4158687" "4341533" "4502983" "4569922" "4581295").PN. OR ("4829027").URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/11/19 14:28
S62 9	18	("4097293" "4141740" "4146379" "4158687" "4341533" "4502983" "4569922" "4581295").PN. OR ("4829027").URPN. and alumina	US-PGPUB; USPAT; USOCR	OR	OFF	2005/11/19 14:28
S63 0	8	("4097293" "4141740" "4146379" "4158687" "4341533" "4502983" "4569922" "4581295").PN. OR ("4829027").URPN. and alumina and (alumina adj nitride)	US-PGPUB; USPAT; USOCR	OR	OFF	2005/11/19 14:28
S63 1	33	"4184882"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S63 2	23	"4800182"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28

S63 3	11	"5376599"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S63 4	11	"5523267"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S63 5	5	"5541143"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S63 6	14	"5134097"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S63 7	23	"4800182"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S63 8	33	"4184882"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S63 9	717	264/123.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S64 0	9	264/123.ccls. and (silicon) and nitride and carbide	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S64 1	104	264/125.ccls. and (silicon) and nitride and carbide	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28
S64 2	1	10/658126	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/19 14:28